

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,547,909 B2
APPLICATION NO. : 10/597607
DATED : June 16, 2009
INVENTOR(S) : Joongseo Park

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Note
Title Page, Item (54) and Column 1, lines 1-3

Please delete "III_NITRIDE COMPOUND ICE SEMICONDUCTOR LIGHT
EMITTING DEV" and insert -III-NITRIDE COMPOUND SEMICONDUCTOR
LIGHT EMITTING DEVICE-

Note
Title Page, Item (22)

Please delete "March 5, 2005" and insert -February 5, 2005-

Note
Title Page, Item (86)

For the filing or '371c' date, delete "August 1, 2006" and insert -August 3,
2006-

Note
This certificate supersedes certificate of correction
issued September 15, 2009.

